Two-photon induced exciton mediated dissociation of N₂O and photomobility of O atoms in crystalline Xe

W. G. Lawrence and V. A. Apkarian
Department of Chemistry, University of California, Irvine, California 92717

(Received 7 May 1992; accepted 24 July 1992)

Two-photon induced access of Xe excitons at 248 nm leads to efficient dissociation of N₂O impurities via ionic potentials. The product O atoms are probed via the Xe⁺O⁻ charge transfer transitions, and the N₂O disappearance is probed by infrared (IR) spectroscopy. Charge transfer excitation of O atoms leads to atomic mobility, such that with extensive irradiation a photochemical steady-state is reached between N₂O, oxygen atoms trapped in the Xe bulk, and within the same cage as N₂. A detailed kinetic analysis of these processes is presented. Among the extracted parameters are the two-photon absorption cross section of Xe at 248 nm, \(3.7 \times 10^{-48} \text{ cm}^4 \text{ s} \), the free exciton migration length, 47 Å, and the excitonic dissociation probability of N₂O, 0.85. The mobility of photoexcited O atoms is attributed to the topology of electronically excited surfaces which show minima at the ground state cage barriers.

I. INTRODUCTION

Photodissociation studies of molecules trapped in rare gas solids often involve intense ultraviolet laser irradiation of highly diluted samples. Under such conditions, the primary irradiation energy may be predominantly deposited in the host lattice via multiphoton processes. Two-photon access of excitonic bands becomes possible for photon energies \(> 4 \text{ eV} \) in Xe, and \(5 \text{ eV} \) in Kr, the cross sections of which have recently been reported.1 Given the large mobilities of free excitons, exciton-impurity encounters are highly probable.2,3 Dissociation of molecular impurities is a possible outcome of an exciton–molecule encounter. We present experimental data from studies of N₂O photodissociation in solid xenon which reveal this mechanism, namely, two-photon induced access of excitonic states and subsequent molecular dissociation due to exciton–molecule encounters.

In the experimental studies to be described, the dissociation of N₂O is followed by monitoring the photogenerated O atoms, and by following the disappearance of N₂O. The first is accomplished by laser-induced fluorescence from the XeO charge transfer states, the spectroscopy of which was recently reported.4 The second is achieved by monitoring N₂O by infrared absorption spectroscopy, details of which were also reported.5 While oxygen atoms in their ground, \(^3\)P, state are permanently trapped,6 excitation to the charge transfer states can lead to mobility. In effect, both O⁻ and O(\(^1\)D) have smaller interaction ranges with the lattice, and the kinetic energy acquired, due to differences in potential gradients in the ground and excited states, is sufficient to give the atoms mobility. Due to the facile migration of photoexcited O atoms, a photochemical steady state is observed between the two-photon dissociation of N₂O and one-photon induced recombination of O atoms. A detailed kinetic analysis of these photoprocesses is presented, and the dynamics is rationalized by the topography of electronic surfaces.

II. EXPERIMENT

The studies were carried out in 1 cm³ free standing, polycrystalline solids. The details of sample preparation have been presented.5 Premixed gas samples of N₂O/Xe (\(\sim 1/10,000 \)) were rapidly deposited onto a cryotip through an insulating mold to form the free standing crystals. An oil diffusion pump with a liquid nitrogen trap was used to maintain vacuum in the cryostat shroud and sample manifold. Xenon of 99.999% purity (Cryogenic Rare Gases), and N₂O of 99.9% purity (Matheson) were used, without further purification. Samples were mixed and stored in 5 l darkened glass bulbs. The large volume of the bulb prevented large changes in back pressure during crystal growth.

N₂O was dissociated and the oxygen atoms were detected using the same laser source. The majority of the experiments to be reported were carried out at 248 nm. Typically, intensities of \(< 10 \text{ mJ/cm}^2 \) in 20 ns pulses were used without focusing. Fluorescence was collected at right angles. Spectra were recorded using a ¼ m polychromator and an optical multichannel analyzer (EG&G OMA) equipped with a gated intensified diode array, with 950 active elements. The detection efficiency of the OMA was calibrated using a standard irradiance lamp with an effective black body temperature of 3100 K (Oriel model 63358). The wavelength calibration of the OMA is made using a Hg/argon pen-lamp. Laser scatter was blocked using a 1 cm path length liquid cell containing toluene, CCl₄, or methanol.

Infrared absorptions were used to monitor the N₂O concentration as a function of irradiation time. The dissociation laser was directed into the cryostat to overlap the infrared (IR) probe. The dissociation laser sources used were either the fourth harmonic of a Nd:YAG laser (Quanta Ray DCR2), or the 248 or 193 nm output of a multigas excimer laser (Lambda Physik EMG 53). To follow the dissociation of N₂O by its IR absorption, CaF₂ windows were used to transmit both the ultraviolet (UV) and IR beams. This limited the spectral range in the IR to...
W. G. Lawrence and V. A. Apkarian: Dissociation of N2O in Xe

Wavelength (nm)

FIG. 1. Temperature dependent emission spectra of Xe+O− after dissociation of N2O at 248 nm. (a) After the initial dissociation of N2O in crystalline xenon shown as the first growth curve in Fig. 5. The concentration of oxygen atoms isolated in xenon is probed by 20 pulses at each temperature. Between 35 and 40 K the emission intensity begins to decrease. (b) The first emission spectrum of the series, labeled 15 i, is the spectrum recorded upon cooling the sample from 50 K (in a) to 15 K. The subsequent spectra are recorded after irradiation and regeneration of the Xe+O− emission shown by the second growth curve in Fig. 5.

frequencies > 1000 cm−1, eliminating the possibility of observing the N2O bending mode.

III. RESULTS

Oxygen atoms in solid Xe can be detected by their charge transfer emissions centered at 375 and 750 nm. In the case of interstitially trapped O atoms, the charge transfer bands can be reached by excitation in the wavelength range of 220–260 nm.4 A sequence of emission spectra, obtained by 248 nm irradiation of the solid, is collected in Fig. 1. The first trace in Fig. 1(a) is obtained after extensive irradiation of the solid at 15 K. The sample is subsequently heated. The emissions subside between 40 and 50 K, but do not disappear completely. Upon cooling of the solid back to 15 K [first trace in Fig. 1(b)] only 10% of the initial intensity is retrieved. Subsequent irradiation of the solid at 15 K [second trace in Fig. 1(b)] regenerates the emission, and the entire process can be repeated. Thus, the photodissociation of N2O to yield O+N2 can be followed by monitoring the growth of these characteristic emissions as a function of irradiation time. Growth curves of XeO, when N2O doped solid Xe of M/R=10 000 are irradiated at 248 nm, are shown in Fig. 2. The initial growth rates show a square dependence on photon flux. This is illustrated in Fig. 2 by showing growth curves at different powers, which when plotted as a function of the square of irradiation intensity, yield identical exponential growth rates. In all cases, the initial exponential growth is followed by a linear slope, a pseudozero order rate of growth. From the exponential fits to the early part of the growth curves, [O]=−[O]o{1−exp(−α(2)φFt)}, an effective two-photon dissociation cross section, α(2)=5.8×10−44 cm4 s is obtained [in which α(2) is a two-photon absorption cross section, and φ is a dissociation quantum yield]. The residual growth is indicative of the fact that the dissociation is not complete. This is verified by following infrared absorptions of N2O.

In Fig. 3, the decay in IR absorptions of N2O when the samples are irradiated at 266, 248, and 193 nm, are shown. Only a fraction of the N2O is dissociated at 266 and 248 nm, 40% and 10%, respectively. The dissociation can be carried out to completion at 193 nm. We note the abscissa in these plots are extended by a factor of 10 beyond that of Fig. 1. The origin of the noise in the data are not well understood. The absorption cross sections of the stretching fundamentals in N2O/Xe show an anomalous temperature dependence.5 That absorption intensities are sensitive to the geometry of the immediate trap cage is to be expected, however not quantified. The determination of the exact fraction of undissociated molecules is subject to uncertainty due to possible mismatches between the UV irradiation volume, and the IR probe volume. This consideration is particularly severe in the case of the 266 nm measurements, since the UV beam has the characteristic doughnut mode profile of the tripled YAG laser used. As such the 40% dissociation limit reached in the case of the 266 nm irradiation should be regarded as an underestimate. It is, however, clear that at 193 nm, where N2O has a strong absorption, one-photon dissociation of the molecule can be carried to completion, a process well characterized recently.

FIG. 2. Growth of Xe+O− emission upon irradiation of an N2O/xenon crystalline sample vs l2n, l=number of deposited laser pulses, at three different intensities (a) 4.2 mJ/cm2; (b) 8.8 mJ/cm2; (c) 16.8 mJ/cm2. The three growth curves are fit to the same exponential which is shown for each curve.

J. Chem. Phys., Vol. 97, No. 9, 1 November 1992

Downloaded 17 Feb 2004 to 128.200.47.19. Redistribution subject to AIP license or copyright, see http://jcp.aip.org/jcp/copyright.jsp
in Xe matrices.\(^6\) \(\text{N}_2\text{O}\) does not have significant absorptions either at 248 nm or at 266 nm. In both cases the dissociation proceeds via a two-photon mechanism. Note however that while 248 nm is strongly absorbed by O/Xe, 266 nm, which corresponds to the threshold of this absorption, is only weakly absorbed.\(^4\)

It is possible to show that with extended 248 nm irradiation a photochemical steady-state is established in the O/Xe concentration. This is established by monitoring the plateau reached in the 750 nm emission. When the photogeneration is carried out at low power and then switched to high power the 750 nm emission grows to a new level. When the plateau is reached at high power, and then switched to low power, the emission intensity decays to a new lower limit. The O atom disappearance is therefore photo-induced. The dependence of the steady-state O atom concentration on pump intensity is illustrated in Fig. 4. The data in this case are collected by imaging the profile of the entire laser irradiated volume on the OMA (laser beam parallel to slit of polychromator). At each intensity, the sample is irradiated for a sufficiently long period to ensure that the emission intensity has reached a plateau. The same results are obtained whether the measurements are conducted as a function of increasing or decreasing laser intensity. Since the process can be reversed by changing laser intensity, it is necessary to conclude that photomobility leads to a sink from which the atoms can be regenerated by irradiation. The possible sinks of O atoms are formation of \(\text{O}_2\), and retrapping of \(\text{O}(^3\text{P})\) next to \(\text{N}_2\) (henceforth designated as \(\text{O}/\text{N}_2\)). For the latter to act as a sink, it is also necessary to assume that O atoms trapped in such sites are either inaccessible or that they do not emit, i.e., charge transfer states of \(\text{XeO}\) are quenched by \(\text{N}_2\) (reactively or otherwise). To test the possibility of \(\text{O}_2\) as the sink of O atoms, studies were carried out in \(\text{O}_2\) doped Xe. Excitation of such solids at 248 nm does not lead to production of O atoms. We can therefore safely assume that a photochemical steady-state is reached between \(\text{N}_2\text{O}\), \(\text{O}/\text{N}_2\), and O/Xe.

In summary, at 248 nm, the early generation of O/Xe from \(\text{N}_2\text{O}\) is two-photon induced. After extensive irradiation, an intensity dependent photochemical steady-state is reached in the isolated O atom concentration. The overall process can therefore be presented by a cyclic kinetic scheme,

\[
\text{N}_2\text{O} + \text{Xe} + 2h\nu \rightarrow \text{O}/\text{Xe} + h\nu \\
\text{O}/\text{N}_2 + h\nu
\]
The new limit reached is usually lower than that prior to
6202 W. G. Lawrence and V. A. Apkarian: Dissociation of N,O in Xe
an N20/xenon sample at 248 nm and the regeneration of the Xe+O-
The initial growth and two regeneration cycles are shown together with
FIG. 5. Initial growth of Xe+O- emission intensity upon irradiation of
warmed up, the O atom emissions subside. This was illus-
trated in Fig. 1. At 50 K, nearly 90% of the emission
intensity is permanently lost, as established by monitoring
the emission after cool-down (the loss is not due to a re-
duced quantum efficiency of fluorescence). Upon subse-
quent irradiation, it is possible to regenerate the emission.
The new limit reached is usually lower than that prior to
heating. This process can be repeated several times with
similar results. The time profiles of emission growth for a
typical set of three thermal cycles is illustrated in Fig. 5.
We note that the growth rates after the thermal cycle are
faster than the initial photogeneration rates. These obser-
vations indicate that thermally activated diffusion of O at-
oms leads to a sink, from which they can be regenerated
very efficiently. As in the above discussion, O2 can be elim-
inated as the sink. That the thermal diffusion does not lead
directly to the formation of N2O is verified by IR spectros-
copy. We are forced to conclude that the sink is O/N2, and
that O atoms at such sites can be reached at 248 nm, but do
not fluoresce. The fast rate of growth after heating the solid
can then be attributed to the photoconversion of O/N2 to
O/Xe. Presumably, the energy released to the lattice, by
quenching the XeO emission, can be used for cage exit of
the O atoms.

From the thermal cycles we conclude that thermally
induced mobility of O atoms leads to trapping of O(3P)
atoms next to N2, and that such atoms can be optically
detrapped into the Xe bulk.

IV. DISCUSSION

The absorption of N2O at 248 nm, which has been
assigned to the forbidden 1Σ-→1Σ+ transition, is very
weak, σ(1)≈10^{-24} cm^2. The two-photon excitation cross
section of Xe at the same wavelength has been measured in
solid Xe to be σ(2)=3.7×10^{-48} cm^4 s. For an optimally
thin sample, the competition between one-photon excita-
tion of an impurity vs the two-photon excitation of the host
can be estimated as

$$\frac{(\Delta I/I)_{(1)}}{(\Delta I/I)_{(2)}} \approx \frac{\sigma(1)}{[I \sigma(2) M/R]}.$$ 

At a typical photon flux of I=1.5×10^{23} photons cm^{-2} s^{-1}
(1 mJ cm^{-2}, 10 ns pulse width, 5 eV photons) and at a
dilution of M/R=10 000, the above ratio yields 10^{-4}, i.e.,
the radiation is primarily deposited in the Xe host. The
two-photon absorption cross section of N2O at 248 nm has
been reported as 3×10^{-45} cm^4 s. Therefore, unless a dra-
imatic enhancement of this cross section (of seven orders of
magnitude) occurs, its effect would be negligible in com-
parison to that of the Xe host.

From the initial rate of growth of O atoms (see Fig. 2),
a two-photon photogeneration rate of 5.8×10^{-44} cm^4 s
is obtained. If we take the dilution factor of N2O of 10^4 into
account, this rate would, within the experimental errors of
measurement, correspond to σ(2), the two-photon absorp-
tion cross section of Xe. Since the measured rate is one of
photogeneration, its agreement with the absorption cross
section would imply that dissociative trapping of the excit-
ons at the N2O sites proceeds with nearly unit probability.
With extended irradiation, absorption by the photogener-
ated O atoms becomes significant. The charge transfer ab-
sorption of O/Xe is centered at 240 nm, with a full-width
at half-maximum (FWHM) of 20 nm, and a radiative life-
time of 227 ns. It is therefore possible to estimate an ab-
sorption cross section of 1×10^{-18} cm^2 at 248 nm. If it
were possible to carry the dissociation of N2O to comple-
tion, quite clearly absorption by O/Xe would dominate all
photoprocesses. Given the 1 cm length of these solids, the
assumption that the sample is optically thin throughout the
irradiation period breaks down. With these considerations
in mind, it becomes clear that a full account of the various
photoprocesses requires a detailed kinetic analysis, for
which we resort to numerical methods.

A. Kinetic model

The photogeneration step is described by the kinetic
equations

$$\text{Xe} + 2h\nu \rightarrow \text{Xe}^* \rightarrow \text{Xe}^{**} \rightarrow \text{O}^{(2)}.$$ (1)
$$\text{Xe}^{**} + \text{N}_2\text{O} \rightarrow \text{N}_2\text{O} \rightarrow \text{O}/\text{N}_2 \rightarrow \text{O}/\text{Xe} \rightarrow \text{Xe}^* \rightarrow \text{Xe}^{**} \rightarrow \text{O}^{(2)}.$$ (2)

in which \text{Xe}^{**} represents a free exciton, while \text{Xe}^*
represents a self-trapped exciton; \text{k}_3 represents the rate constant
for self-trapping, and self-trapped excitons are assumed to
decay without further dynamics of relevance. The exciton
encounter with N2O is characteristic of the bimolecular
rate constant \text{k}_2 in Eqs. (2). The important model param-
eter with respect to the excitonic dynamics is \text{k}_2/\text{k}_3, which
represents the volume spanned by the free exciton prior to self-trapping. Upon trapping at an $\text{N}_2\text{O}$ site, three possible outcomes are anticipated, quenching of the exciton by energy transfer to $\text{N}_2\text{O}$ (2a), dissociation of $\text{N}_2\text{O}$ without cage exit of fragments (2b), and dissociation by cage exit of the O atoms (2c). Note that $\phi_{21} + \phi_{22} + \phi_{23} = 1$.

The photomobility of O atoms excited at 248 nm is represented by

$$\text{O/}\text{Xe} + h\nu \rightarrow \text{Xe}^+\text{O}^- \rightarrow \text{O/}\text{Xe} + h\nu' \quad ; \quad \sigma_1\phi_{41} \quad \text{(4a)}$$

$$\rightarrow \text{O}/\text{N}_2 \quad ; \quad \sigma_1\phi_{42} \quad \text{(4b)}$$

$$ \rightarrow \text{N}_2\text{O} \quad ; \quad \sigma_1\phi_{43} \quad \text{(4c)}$$

in which it is assumed that the charge transfer absorption of O atoms trapped in the Xe bulk, with an absorption cross section of $\sigma_1$, proceeds via three possible outcomes, radiative relaxation with no further dynamics (4a), photomobility leading to re-entry of the initial cage (4b), and photomobility leading to recombination with $\text{N}_2$ (4c). The process of Eq. (4b) would be consistent with cage reentry of an O atom on the $^3\text{P}$ surface, while Eq. (4c) would be consistent with re-entry either as $\text{O}^-$ or $\text{O}(^1\text{D})$.

The above kinetic equations cannot account for the thermal cycling experiments in which a faster rate of O atom growth is observed after heating the solids. Thermal loss of O atoms necessarily proceeds on the $^3\text{P}$ surface, and will therefore lead to formation of $\text{O}/\text{N}_2$. Explicit account of regeneration of $\text{O}/\text{Xe}$ from such sites is necessary.

$$\text{O}/\text{N}_2 + h\nu \rightarrow \text{Xe}^+\text{O}^- \rightarrow \text{O}/\text{N}_2 \quad ; \quad \sigma_2\phi_{51} \quad \text{(5a)}$$

$$\rightarrow \text{O}/\text{Xe} \quad ; \quad \sigma_2\phi_{52} \quad \text{(5b)}$$

$$ \rightarrow \text{N}_2\text{O} \quad ; \quad \sigma_2\phi_{53} \quad \text{(5c)}$$

In Eq. (5), the charge transfer absorption of O atoms trapped in the same cage as $\text{N}_2$ is considered with the three possible outcomes of quenching without further dynamics (5a), cage exit (5b), and recombination within the cage (5c). Note the absorption cross section in Eq. (5) need not be the same as the absorption cross section in Eq. (4).

Given the short lifetime of free excitons, ~1 ps, a steady-state assumption in Xe** within the laser pulse is valid, [Xe**] = $\sigma^{(2)}[\text{Xe}] I' / ([\text{N}_2\text{O}] k_2 + k_3)$. (6)

As mentioned above, it is also necessary to take explicit account of the radiation intensity as it traverses the 1 cm path length of the solid, in the kinetic analysis. The coupled rate expressions that are numerically integrated are

$$\frac{d}{dt}[\text{O}/\text{N}_2] = -[\text{Xe}^*][\text{N}_2\text{O}] k_2(\phi_{22} + \phi_{23})$$

$$+ [\text{O}/\text{Xe}] \sigma_1\phi_{43} + [\text{O}/\text{N}_2] \sigma_2\phi_{53}, \quad \text{(7)}$$

$$\frac{d}{dt}[\text{O}/\text{Xe}] = [\text{Xe}^*][\text{N}_2\text{O}] k_2\phi_{23} + [\text{O}/\text{Xe}] \sigma_2\phi_{52}$$

$$- [\text{O}/\text{Xe}] \sigma_1(\phi_{42} + \phi_{43}), \quad \text{(8)}$$

The integration is carried out in both time and space. The latter is achieved by slicing the solid along the length of propagation of the radiation into optically thin segments, such that $\Delta l/l < 0.01$ in each segment. The total $\text{N}_2\text{O}$ concentration is summed over the entire length of the solid, to represent the concentrations that would be observed in the IR experiments. The instantaneous product of the radiation intensity and the $\text{O}/\text{Xe}$ concentration in each segment is summed over all segments to represent the $\text{Xe}^+\text{O}^-$ emission intensity measured in the fluorescence experiments.

The numerical solutions are then compared to the experiments, and the best fit parameters are obtained by iteration. We require the O atom concentration as a function of time to reproduce the photogeneration curves prior and subsequent to heat cycling, and the fractional $\text{N}_2\text{O}$ loss at the end of the photogeneration to reproduce the IR measurement. Iteration of these solutions yields the set of rate constants and branching ratios collected in Table I. The time profiles simulated with these constants are shown together with the experimental data in Fig. 5.

The steady-state concentration of $\text{O}/\text{Xe}$ as a function of pump intensity, shown in Fig. 4, represents an additional test of the model parameters. For the cyclic equilibrium, taking mass conservation into account, the equilibrium concentrations of the three species $\text{O}/\text{Xe}^*$, $\text{N}_2\text{O}$, $\text{O}/\text{N}_2$ can be related as

TABLE I. Kinetic parameters.

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Value</th>
</tr>
</thead>
<tbody>
<tr>
<td>$\sigma^{(2)}$ (cm$^2$ s$^{-1}$)</td>
<td>3.7 x 10^{-48}</td>
</tr>
<tr>
<td>$k_2/k_3$ (cm$^3$)</td>
<td>1 x 10^{-19}</td>
</tr>
<tr>
<td>$l$ (Å)</td>
<td>47</td>
</tr>
<tr>
<td>$\sigma_1$ (cm$^2$)</td>
<td>8 x 10^{-19}</td>
</tr>
<tr>
<td>$\sigma_2$ (cm$^2$)</td>
<td>9.5 x 10^{-20}</td>
</tr>
<tr>
<td>$\phi_{21}$</td>
<td>0.15</td>
</tr>
<tr>
<td>$\phi_{22}$</td>
<td>0.00</td>
</tr>
<tr>
<td>$\phi_{23}$</td>
<td>0.83</td>
</tr>
<tr>
<td>$\phi_{41}$</td>
<td>0.365</td>
</tr>
<tr>
<td>$\phi_{42}$</td>
<td>0.43</td>
</tr>
<tr>
<td>$\phi_{43}$</td>
<td>0.205</td>
</tr>
<tr>
<td>$\phi_{51}$</td>
<td>0.08</td>
</tr>
<tr>
<td>$\phi_{52}$</td>
<td>0.71</td>
</tr>
<tr>
<td>$\phi_{53}$</td>
<td>0.21</td>
</tr>
</tbody>
</table>

$^a$Reference 1.
$^b$Reference 9, p. 237.
$^c$Reference 3.
$^d$Estimated based on excitation spectrum and radiative lifetime of $\text{Xe}^+\text{O}^-$ in Xe, from Ref. 4.
\[
1/([O/Xe])_e = 1 + [N_2O]/[O/Xe] + [O/N_2]/([O/Xe])_e \tag{11a}
\]
\[
= 1 + 0.43/(I\sigma(2)\phi_{23}[Xe]k_2/k_3) + 0.42/\phi_{25}. \tag{11b}
\]

Therefore, a plot of \(1/([O/Xe])_e\) vs \(1/I\) should yield the equilibrium ratio of \([O/N_2]/[O/Xe]\) as its intercept, and the slope determines the equilibrium ratio of \([N_2O]/[O/Xe]\). Note however, that Eq. (11) is valid for an optically thin sample. In the present case, it is necessary to consider the laser intensity profile, and the associated concentration profiles along the length of the solid. This is achieved by spatial integration of \(l\).

\[
I_e = I_0 - \int \{I\sigma(2)[Xe] + I\sigma_1[O/Xe] + I\sigma_2[O/N_2]\}dz. \tag{12}
\]

Using Eq. (12), the equilibrium concentrations in optically thin slabs along the laser propagation are determined according to Eq. (11), and the observed steady-state signal is then related to \(I [O/Xe]dz\) after normalization. Using the kinetic parameters of Table I, which were determined from the fits to time profiles, the dependence of the XeO steady-state emission on pump power is well reproduced, as illustrated in Fig. 4.

The simulations of photogeneration are carried out for a total irradiation of \(3 \times 10^{19}\) photons \(cm^{-2}\). At the end of this period, 5% dissociation of \(N_2O\) is predicted. According to the IR spectra, the experiments show 8% dissociation. Given the scatter in the IR data, the agreement is deemed satisfactory.

In principle, there are ten independent variables in the simulated kinetics. These are the three absorption cross sections \(\sigma(2), \sigma_1,\) and \(\sigma_2\), the volume spanned by the free exciton \(k_2/k_3\), and two independent branching ratios in each of the processes of Eqs. (2), (4), and (5). These are determined by the following experimental observables: (a) The XeO growth profile at different laser intensities subject to two initial conditions. In the first photogeneration cycle \([N_2O]/[O/\text{Xe}] = [O/N_2] = 0\); and subsequent to heating \([N_2O]/[O/\text{Xe}] = 0, [O/N_2] = 0\). (b) The XeO steady-state concentration as a function of pump intensity. (c) The \(N_2O\) time profiles as observed by the IR absorption measurements. The reproduction of all of these observables, with one set of kinetic parameters leads us to believe that, within the assumptions of the model, the parameters are well determined.

Independent checks exist for several of the determined parameters, and these are collected in Table I. The value derived from the simulations for the two-photon absorption cross section of Xe, \(\sigma(2) = 3.7 \times 10^{-48}\) \(cm^4s\), is identical to that reported in Ref. 1. This exact agreement is fortuitous, since the measurements are subject to significant experimental error (\(\sim 50\%\) due to uncertainties associated with laser beam waist profile in the solid). From \(k_2/k_3\) the diffusion range of free excitons in Xe, \(I = (k_2/k_3)^{1/2} = 47\) \(\AA\), is determined to be consistent with prior measurements, which range between 25–260 \(\AA\) (see Table I). The absorption cross section of \(O/Xe\), \(\sigma_1 = 8 \times 10^{-19}\) \(cm^2\), agrees with the estimate of this cross section based on its radiative lifetime and excitation profile. The absorption cross section of \(O/N_2\) is mainly determined by the growth rates subsequent to heating the solid. A smaller value for this cross section than that of \(O/Xe\) is to be expected since \(O/N_2\) corresponds to isolation of \(O\) atoms in sites that are significantly looser than interstitial traps.

The dissociation limit of \(N_2O\) is determined by two effects (a) the reduction of the radiation field due to the \(O/Xe\) absorption, hence the reduced rate of two-photon absorption; (b) photoinduced regeneration of \(N_2O\) by the product oxygen atoms \(O/Xe\) and \(O/N_2\). Note, although the absorption of \(O/N_2\) is much smaller than that of \(O/Xe\), its equilibrium concentration is much larger. At equilibrium, according to Eq. (11), \([O/N_2]/[O/Xe] = 0.43/\phi_{25} = 5.1\). Therefore, the main product of \(N_2O\) dissociation are photofragments trapped within the same cage.

The increased extent of dissociation at 266 nm is consistent with the above interpretation. The two photon excitation of the bulk xenon is expected to be similar for both 248 and 266 nm, but the oxygen atom photoproducts are not excited at 266 nm. Nevertheless, even after long periods of irradiation at 266 nm, according to the IR spectra, the \(N_2O\) dissociation is not complete. Using the same kinetic model, with the assumption of \(O\) atom absorption cross sections 100 times smaller, 13% dissociation of \(N_2O\) is predicted after deposition of \(3 \times 10^{19}\) photons \(cm^{-2}\) at 266 nm, as compared to the experimental value of 20%. Thus, although not studied in the same depth as the 248 nm data, the 266 nm data are consistently interpreted with the same kinetic model.

### B. Mechanism

At the 8–10 eV of excitonic energy available to \(N_2O\) a variety of dissociative channels leading to \(O(1S, 1D)\) + \(N_2(1\Sigma, 1\Pi)\), \(O(1^2P)\) + \(N_2(1\Sigma, 1\Pi)\), or \(NO(1\Pi)\) + \(N^*(2^2D, 2^2P)\) are energetically possible. Such dissociation products have previously been observed in vacuum ultraviolet (VUV) excited solid samples. However, we see no direct evidence for any of these channels. We do not observe any detectable transient emissions from any atomic or molecular excited electronic states, and we have failed to see the formation of \(NO\) in the IR spectra. Although some of these dissociation channels would be difficult to eliminate without further experimental scrutiny, it is clear that the dissociation mechanism is not indiscriminate. This conclusion is reinforced by the absence of exciton mediated dissociation in \(O_2\) doped solid \(Xe\). Furthermore, the thermal recombination dynamics and photomobility induced steady-state dynamics observed in the present is quite different from that observed by 193 nm dissociation of \(N_2O\) in solid \(Xe\), which proceeds via \(N_2(1\Sigma) + O(1^2D)\) channel. As we have shown, the photodissociation of \(N_2O\) at 193 nm can be carried out to completion, and it has been shown that subsequent 248 nm irradiation of such solids leads to photodiffusion dominated by formation of \(O_2\) instead of recombination. The exciton induced dissociation of \(N_2O\) can therefore safely be ascribed to a specific channel,
It has been well established in gas phase studies that excited rare gas atoms, due to their reduced ionization energies, can be regarded as pseudo-alkalis, and as such can undergo harpoon reactions. More specifically, the harpoon reaction of N₂O with Xe*(6p) has been shown to be rather efficient,\(^\text{12-15}\)

\[
\text{Xe*} + \text{N}_2\text{O} \rightarrow \text{Xe}^+\text{N}_2\text{O}^- \rightarrow \text{N}_2 + \text{Xe}^+\text{O}^-.
\]

(13)

The same mechanism nicely explains the observed dynamics in the present. In contrast with the gas phase, where the ionic potentials are inaccessible for Xe(6s),\(^\text{14}\) due to solvation of ionic potentials, the energetic threshold for the entrance channel should be significantly lowered. This is consistent with the observation that two-photon excitation at 248 and 266 nm, which lead to the \(n = 2, J = 1/2\) and \(n = 3, J = 3/2\) excitons in Xe (Wannier notation),\(^\text{3}\) are equally efficient in the photogeneration of O atoms. This mechanism, as in the gas phase, also explains the absence of O atom photogeneration in O₂ doped solids despite the fact that the Xe⁺O⁻ surface is energetically accessible. The nonreactivity in the case of O₂ is attributed to the stability of the O⁻ radical, in contrast with N₂O⁻ which is dissociative.\(^\text{14}\)

The analogies with gas phase harpoon reactions and those in condensed media are strikingly similar. This has been borne out by our previous two-photon induced harpoon reactions with halogens in which intermolecular charge transfer states are accessed directly.\(^\text{16}\) In general, in polarizable media, this ionic mechanism is observed to proceed with very large probabilities for cage exit of fragments. In fact, a “negative” cage effect has been postulated, i.e., one in which the cage atoms assist in the ejection of fragments.\(^\text{16}\) The same is observed in the present. According to the kinetic analysis, the cage exit probability of O atoms in the present case is rather large, \(\phi_{22} = 0.85\). This process competes with recombination, and no in-cage dissociation is observed, \(\phi_{23} = 0\), although allowance is made for this channel in the kinetic analysis. An implication is that the cage exit does not proceed on the O⁺(3P) surface, but rather on the ionic surface. The Xe⁺O⁻ potentials are predissociative due to crossings with O⁺(1D) and O⁺(1S) surfaces. Thus, if such a surface hop occurs within the cage, recombination with N₂ should be expected. This presumably accounts for the recombinaton probability of \(\phi_{21} = 0.15\). Finally, dissociation via the ionic channel, assisted by the polarizable cage, would imply that the photoproducts are isolated as nearest neighbors. This would explain the effective thermal and photo-induced cage re-entry of O atoms. In contrast, the photo-induced recombination of O atoms generated by 193 nm irradiation is more consistent with photofragments that are separated by several lattice sites.\(^\text{6,17}\) This is consistent with the N₂+O⁺(1D) channel, and the expectation of facile mobility for O⁺(1D), which is argued below.

Independent of the details of the dissociation channels, it is clear that photoexcitation of O atoms leads to facile crossing of cage barriers—O atoms are photomobile. We observe cage reentry with \(\sim 20\%\) probability of recombination with N₂ (\(\phi_{23} = 0.205\)). This channel is only consistent for migration of electronically excited O atoms. The observed formation of O/N₂ by photomobility of O atoms is not in contradiction with this expectation. Broadside collision of excited atoms with N₂ could lead to quenching to form O⁺(3P) trapped next to N₂. However, the observations that the generation of Xe⁺O⁻ within the cage containing N₂ does not yield O/N₂ with any significant probability (\(\phi_{21} = 0.08\) and \(\phi_{22} = 0\)) would argue that the observed cage re-entry of photo-mobilized atoms mainly proceeds via the O⁺(1D) surface.

Extensive photomobility of ground state F atoms has been documented previously both by experiment\(^\text{18}\) and theory.\(^\text{19}\) In effect F atoms are “small,” as judged by F–Rg pair potentials. In fact, based on diatomic potential parameters, potential minimum and repulsive wall, of all known ground state atoms, F has the shortest interaction range with rare gases. The diatomic pair potentials of Xe–O have been calculated,\(^\text{20}\) and the ground state potential has been extracted from molecular beam scattering data.\(^\text{21}\) These have been recently shown to be at least qualitatively consistent with the observed spectroscopy in solid Xe.\(^\text{4}\) The interaction is quite repulsive in the ground 3P state, and it is clear that trapping in this state is stable. In contrast, O⁺(1D) forms a bound potential 1Σ⁺ with an internuclear separation of 2.2 Å,\(^\text{4}\) more than 1 Å shorter than in the ground state minimum, which occurs near 3.7 Å. In this excited state, the O atom has shrunk to a size comparable to F.

Consideration of the dividing surfaces that must be crossed for atomic mobility from one lattice site to another, for different electronic configurations, is quite illuminating. Exact multidimensional surfaces are not available. However, relying on the spectroscopic information available, schematic surfaces, correlation diagrams, can be constructed. Consider a fcc solid with an O atom trapped at the octahedral interstitial site, which is believed to be the populated site. The minimum energy path to cross to a new equivalent site requires passage through the D_{3h} window, via a curved path, as indicated in Fig. 6. The internuclear distance between an impurity atom trapped in this condition...
provide a better rationalization as to the origin of recursions on this surface. Essentially, in the window, the O(\(^1\Sigma^+\)) atoms are bound along all directions and may only relax by curve crossing to the triplet surface. Similar dynamics should prevail in the ionic surface. Since O\(^-\) fits well in the cage windows, it will experience a potential minimum there. Curve crossing to neutral potentials can therefore carry the atom to the octahedral sites.

V. CONCLUSIONS

In highly diluted rare gas solids, UV laser irradiation can lead to multiphoton access of excitonic states, and exciton-induced dissociation of impurities becomes an important photodissociation mechanism for impurities in which the negative ion is unbound. Exciton induced dissociation of molecular impurities by direct optical access of rare gas excitons has previously been observed. Of particular relevance to the present are the studies on N\(_2\)O, CO\(_2\), and O\(_2\) doped krypton and Xe matrices\(^{22-24}\). The harpooning mechanism had been invoked in the interpretation of the data.\(^{23}\) In the case of N\(_2\)O doped Xe solids, specific production of O(\(^3\)P) is concluded. However we have reassigned the emission used in this interpretation to Xe+O\(^-\),\(^4\) and therefore the exciton induced reactions should be reassigned to the ionic channel. It should also be pointed out that these VUV studies do not distinguish between emissions due to permanent dissociation vs transient species which may undergo in-cage recombination. The kinetic analysis in the present provides a rather clear picture of the dominant dynamics of permanent reactions.

Extensive photomobility of O atoms via access of charge transfer potentials is observed, and rationalized by the topology of excited electronic surfaces. While exact surfaces do not yet exist, schematic correlations along the cage exit coordinate reveal that although a cage barrier exists in the ground state of O atoms, in both O(\(^1\)D) and O\(^-\), minima develop at the dividing surface between trapping sites. It can be therefore predicted that extensive long-range mobility of O atoms should be observed on the \(^1\)D state, and site-to-site hopping should be observed on the ionic surface. The distinction between these two is based on the nature of the potentials; while additivity is present in the neutral potentials, the ionic potentials in this case are believed to be highly localized.

It should be clear that the photochemistry observed in these systems is strongly controlled by nonadiabatic dynamics. As such a deeper understanding of the many-body electronic surfaces, and their couplings is essential for detailed analyses. There is a need for theoretical treatments of multisurface dynamics in these model systems.

ACKNOWLEDGMENTS

This research was supported by the U.S. Air Force Phillips Laboratory under Contract No. S04611-90-K-0035, and by a grant from the National Science Foundation, ECS-8914321. The 266 nm experiments, and the IR studies were conducted in the Laser Spectroscopy Facility

FIG. 7. A schematic of the potential energy surface cuts along the coordinate of Fig. 6, for O atoms in solid Xe. The potentials are based on the spectroscopic analysis in Ref. 4.
of the Department of Chemistry at UCI. Useful discussions with Professor N. Schwentner and D. Imre, are gratefully acknowledged.

17. E. Weitz (private communications).